#### MAX14882

## **5kV<sub>RMS</sub>** Isolated CAN Transceiver with Integrated Transformer Driver

### **General Description**

The MAX14882 isolated high-speed CAN transceiver improves communication and safety by integrating galvanic isolation between the CAN-protocol controller-side (TDX, RXD) of the device and the physical wires of the CAN network (CANH, CANL) cable-side/bus-side of the transceiver. Isolation improves communication by breaking ground loops and reduces noise where large differences in ground potentials exists between ports. The MAX14882 provides up to 5000V<sub>RMS</sub> (60s) of galvanic isolation and a continuous working voltage of up to 848V<sub>RMS</sub>, while operating at the maximum high-speed CAN data rate of 1Mbps.

The MAX14882 features additional integrated protection for robust communication. The  $\pm 25$ V receiver input commonmode range exceeds the ISO 11898 specification requirement of -2V to +7V. Additionally, the CANH and CANL IOs are fault tolerant up to  $\pm 54$ V and are protected from electrostatic discharge (ESD) up to  $\pm 15$ kV to GNDB on the bus-side, as specified by the Human Body Model (HBM).

Interfacing with CAN-protocol controllers is simplified by the wide 3.0V to 5.5V supply voltage range ( $V_{DDA}$ ) on the controller-side of the device. The supply voltage range for the CAN bus-side of the device is 4.5V to 5.5V ( $V_{DDB}$ ). An integrated transformer driver and LDO can be used, with an external transformer, to generate the isolated supply for  $V_{DDB}$ .

Field installation and troubleshooting are simplified by the polarity select (POL) input. POL swaps the functions of the CANH and CANL IOs, allowing for simple software correction of cross-wired bus cables in the field.

The MAX14882 operates over the -40°C to +125°C temperature range and is available in a 16-pin wide SOIC (W SOIC) package with 8mm of creepage and clearance.

### **Applications**

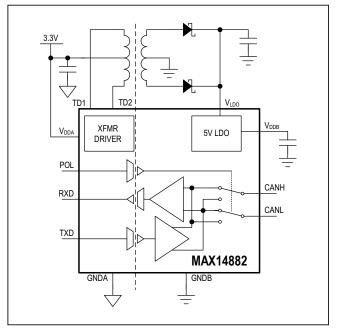
- Building Automation
- Industrial Controls
- HVAC
- Switching Gear

### **Benefits and Features**

- Integrated Protection for More Robust Communication
  - 5kV<sub>RMS</sub> Withstand Galvanic Isolation (60s)
  - ±25V Common Mode Range
  - ±54V Fault Protection
  - ±15kV ESD (HBM) Protection on Driver Outputs/ Receiver Inputs
- High-Performance Transceiver Enables Flexible Designs
  - Wide 3.0V to 5.5V Supply Voltage Range for CAN Controller Interface
  - Field Bus Polarity Control (POL)
  - Integrated Transformer Driver for Power Transfer to Bus-Side
  - · Integrated LDO for Powering CAN Bus-Side
- Safety Regulatory Approvals (Pending)
  - UL1577 (Basic Insulation)
  - · cUL According to CSA Bulletin 5A

Ordering Information appears at end of data sheet.

## Simplified Block Diagram





### **Absolute Maximum Ratings**

V <sub>DDA</sub> to GNDA	0.3V to +6V	Short-Circuit Duration (RXD to GNDA or \	DDA)Continuous
V <sub>DDB</sub> to GNDB	0.3V to +6V	TD1, TD2 Continuous Current	±1.4A
V <sub>LDO</sub> to GNDB	0.3V to +16V	Continuous Power Dissipation (T <sub>A</sub> = +70°	C)
TD1,TD2 to GNDA	0.3V to +12V	16-pin W SOIC (Derate 14.1mW/°C above	e +70°C) 1126.8mW
TXD, POL to GNDA	0.3V to +6V	Operating Temperature Range	40°C to +125°C
RXD to GNDA0.3	3V to (V <sub>DDA</sub> + 0.3V)	Junction Temperature	+150°C
I.C. to GNDB0.3	3V to (V <sub>DDB</sub> + 0.3V)	Storage Temperature Range	60°C to +150°C
CANH or CANL to GNDB (Continuous)	54V to +54V	Lead Temperature (soldering, 10s)	+300°C
Short-Circuit Duration (CANH to CANL)	Continuous	Soldering Temperature (reflow)	+260°C
Short Circuit Duration (CAN to GNDB or V	DDB)Continuous		

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## **Package Information**

### Wide 16-SOIC

W16+10
21-0042
90-0107
107 °C/W
22 °C/W
71 °C/W
23 °C/W

For the latest package outline information and land patterns (footprints), go to <a href="www.maximintegrated.com/packages">www.maximintegrated.com/packages</a>. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a four-layer board. For detailed information on package thermal considerations, refer to <a href="https://www.maximintegrated.com/thermal-tutorial">www.maximintegrated.com/thermal-tutorial</a>.

#### **Electrical Characteristics**

 $(V_{DDA} = 3.0V \text{ to } 5.5V, V_{DDB} = 4.5V \text{ to } 5.5V, POL = GNDA, I.C. = GNDB, T_A = -40^{\circ}C \text{ to } +125^{\circ}C.$  Typical values are at  $V_{DDA} = 3.3V, V_{DDB} = 5V, GNDA = GNDB, and T_A = +25^{\circ}C, unless otherwise noted. (Notes 1, 2) )$ 

PARAMETER	SYMBOL	СО	MIN	TYP	MAX	UNITS	
POWER							
Controller-Side (A-Side) Voltage Supply	V <sub>DDA</sub>			3		5.5	V
Bus-Side (B-Side) Voltage Supply	V <sub>DDB</sub>			4.5		5.5	V
Controller Side (A-Side)		POL = TXD = high or low, RXD	V <sub>DDA</sub> = 5V		4.7	7.7	
Supply Current	I <sub>DDA</sub>	unconnected, TD1/TD2 uncon- nected	V <sub>DDA</sub> = 3.3V		4.5	7.5	mA

## **Electrical Characteristics (continued)**

( $V_{DDA}$  = 3.0V to 5.5V,  $V_{DDB}$  = 4.5V to 5.5V, POL =GNDA, I.C. = GNDB,  $T_A$  = -40°C to +125°C. Typical values are at  $V_{DDA}$  = 3.3V,  $V_{DDB}$  = 5V, GNDA = GNDB, and  $T_A$  = +25°C, unless otherwise noted. (Notes 1, 2) )

PARAMETER	SYMBOL	СО	NDITIONS	MIN	TYP	MAX	UNITS
			TXD = GNDA, R <sub>L</sub> = open		9.4	15.5	
			TXD = GNDA, $R_L = 60\Omega$		52	76	1
Bus-Side (B-Side) Supply			TXD = $V_{DDA}$ , $R_L = 60\Omega$		8.5		]
Current	I <sub>DDB</sub>	V <sub>DDB</sub> = 5V	TXD = GNDA, CANH shorted to CANL		98	130	mA
			TXD = V <sub>DDA</sub> , CANH shorted to CANL		8.5		
Controller-Side (A-Side)			RXD, TXD, POL			1.66	V
Undervoltage Lockout Threshold	V <sub>UVLOA</sub>	V <sub>DDA</sub> rising	TD1, TD2			2.85	
Controller-Side (A-Side)	V	\/ falling	RXD, TXD, POL		50		\/
UVLO Hysteresis	VUVLOA_HYST	V <sub>DDA</sub> falling	TD1, TD2		200		mV
Bus-Side (B-Side) Under-	.,	V <sub>DDB</sub> rising	,			4.25	.,
voltage Lockout Threshold	V <sub>UVLOB</sub>	V <sub>DDB</sub> falling		3.45			V
TRANSFORMER DRIVER							
TD1, TD2 Output Resistance	RO	TD1/TD2 = low, I <sub>TD</sub>	= 300mA		0.6	1.5	Ω
TD4 TD0 0		4.5V ≤ V <sub>DDA</sub> ≤ 5.5V	1	540	785	1300	A
TD1, TD2 Current Limit	I <sub>LIM</sub>	3.0V ≤ V <sub>DDA</sub> ≤ 3.6V	,	485	730	1170	mA
Switching Frequency	f <sub>SW</sub>		350	450	550	kHz	
Duty Cycle	D			50		%	
Crossover Dead Time	t <sub>DEAD</sub>				50		ns
LDO							
LDO Supply Voltage	V <sub>LDO</sub>	(Note 3)		4.68		14	V
LDO Output Voltage	$V_{DDB}$			4.5	5	5.5	V
LDO Current Limit					300		mA
Load Regulation		V <sub>LDO</sub> = 6V, I <sub>LOAD</sub> =	20mA to 40mA		0.19		mV/mA
Line Regulation		$V_{LDO}$ = 6V to 9.5V,	I <sub>LOAD</sub> = 20mA		0.12	1.8	mV/V
Dropout Voltage		V <sub>LDO</sub> = 4.68V, I <sub>DDB</sub>	= -120mA		100	180	mV
Load Capacitance		Nominal value (Note	es 4, 5)	1		10	μF
CAN BUS DRIVER							
Dominant Output Voltage	W	TXD = GNDA,	CANH, POL = GNDA	2.75		4.5	
High	V <sub>CAN_DH</sub>	$50\Omega \le R_L \le \text{to } 65\Omega$	CANL, POL = V <sub>DDA</sub>	2.75		4.5	V
Dominant Output Voltage	V	TXD = GNDA,	CANH, POL = GNDA	0.5	,	2.25	\/
Low	V <sub>CAN_DL</sub>	$50\Omega \le R_L \le \text{to } 65\Omega$	CANL, POL = V <sub>DDA</sub>	0.5		2.25	V
			R <sub>CM</sub> = Open	1.5		3	
Dominant Output Voltage,	· Vob		$R_{CM} = 1.25k\Omega$ , -17V $\leq V_{CM} \leq +17V$	1.5		3	
Differential		Figure 1	$R_{CM} = 1.25k\Omega$ , $-25V \le V_{CM} \le +25V$	1.1		3	

## **Electrical Characteristics (continued)**

( $V_{DDA}$  = 3.0V to 5.5V,  $V_{DDB}$  = 4.5V to 5.5V, POL =GNDA, I.C. = GNDB,  $T_A$  = -40°C to +125°C. Typical values are at  $V_{DDA}$  = 3.3V,  $V_{DDB}$  = 5V, GNDA = GNDB, and  $T_A$  = +25°C, unless otherwise noted. (Notes 1, 2) )

PARAMETER	SYMBOL	С	ONDITIONS	MIN	TYP	MAX	UNITS
CANH Recessive Output Voltage	V <sub>CAN_HR</sub>	TXD = V <sub>DDA</sub> , no I	oad	2		3	V
CANL Recessive Output Voltage	V <sub>CAN_RL</sub>	TXD = V <sub>DDA</sub> , no I	oad	2		3	V
Recessive Output Voltage,		TVD = \/	$R_L = 60\Omega$	-12		+12	m\/
Differential		$TXD = V_{DDA}$	R <sub>L</sub> = Open	-50		+50	mV
High-Side Short-Circuit	lauanz u	TXD = GNDA	POL = GNDA, CANH = GNDB	50	75	100	- mA
Current	<sup>I</sup> SHORT_H	IND - GNDA	POL = V <sub>DDA</sub> , CANL = GNDB	50	75	100	
Low-Side Short-Circuit	la	TXD = GNDA	POL = GNDA, CANL = V <sub>DDB</sub>	50	75	100	- mA
Current	ISHORT_L	TAD - GNDA	POL = V <sub>DDA</sub> , CANH = V <sub>DDB</sub>	50	75	100	IIIA
RECEIVER							
Common Mode Input Range		CANH or CANL to	CANH or CANL to GNDB, RXD output valid				V
Differential Input Voltage (Recessive)	$V_{ID\_R}$	IVCANH - VCANLI,	0.5			V	
Differential Input Voltage (Dominant)	V <sub>ID_D</sub>	IVCANH - VCANLI,			0.9	V	
Differential Input Hysteresis					125		mV
Common-Mode Input Resistance	R <sub>IN</sub>	TXD = V <sub>DDA</sub> , R <sub>IN</sub>	= $\Delta V/\Delta I$ , $\Delta V$ = +300mV	10		50	kΩ
Differential Input Resistance	R <sub>DIFF_IN</sub>	TXD = V <sub>DDA</sub> , R <sub>IN</sub>	= ΔV/ΔI, ΔV = +300mV	20		100	kΩ
Input Leakage Current	_	V <sub>DDB</sub> = GNDB, V	CANH = V <sub>CANL</sub> = 5V			310	μA
Input Capacitance		CANH or CANL to	GNDB, T <sub>A</sub> = +25°C (Note 4)		14.4	20	pF
Differential Input Capacitance		CANH to CANL, T	A = +25°C (Note 4)		7.2	10	pF
LOGIC INTERFACE (RXD, TX	KD, POL)						
Input High Voltage	V <sub>IH</sub>	POL, TXD to GNE	)A	0.7 x V <sub>DDA</sub>			V
Input Low Voltage	V <sub>IL</sub>	POL, TXD to GNDA				0.8	V
Input Hysteresis	V <sub>HYS</sub>				220		mV
Output High Voltage	V <sub>OH</sub>	RXD, I <sub>OUT</sub> = -4mA		V <sub>DDA</sub> - 0.4			V
Output Low Voltage	V <sub>OL</sub>	RXD, I <sub>OUT</sub> = 4mA			0.4	V	
Input Pullup Current	I <sub>PU</sub>	TXD	-10	-4.5	-1.5	μA	
Input Pulldown Current	I <sub>PD</sub>	POL		1.5	4.5	10	μA
Input Capacitance	C <sub>IN</sub>				2		pF

## **Electrical Characteristics (continued)**

( $V_{DDA}$  = 3.0V to 5.5V,  $V_{DDB}$  = 4.5V to 5.5V, POL =GNDA, I.C. = GNDB,  $T_A$  = -40°C to +125°C. Typical values are at  $V_{DDA}$  = 3.3V,  $V_{DDB}$  = 5V, GNDA = GNDB, and  $T_A$  = +25°C, unless otherwise noted. (Notes 1, 2) )

PARAMETER	SYMBOL	CO	NDITIONS	MIN	TYP	MAX	UNITS
PROTECTION					-	,	
Fault Protection Range		CANH, CANL to GN	IDB	-54		+54	V
		IEC 61000-4-2 Air-0		±10			
ESD Protection (CANH and CANL to GNDB)		IEC 61000-4-2 Contact Discharge			±5		kV
(CAINH and CAINE to GINDB)		Human Body Model	(HBM)		±15		1
		IEC 61000-4-2 Con	tact Discharge		±3		
ESD Protection (CANH and CANL to GNDA)		IEC 61000-4-2 Air G 470pF capacitor cor and GNDB	Gap Discharge. nnected between GNDA		±10		kV
ESD Protection (All Other Pins)		Human Body Model	(HBM)		±2		kV
Thermal Shutdown	T <sub>SHDN</sub>	Junction temperatur	e rising		+160		°C
Thermal Shutdown Hysteresis	T <sub>SH_HYST</sub>				13		°C
SWITCHING CHARACTERIS	TICS						
Common-Mode Transient Immunity	CMTI	(Note 6)			35		kV/µs
Driver Rise Time	$t_{R}$	R <sub>CM</sub> is open, R <sub>L</sub> = 6			23	ns	
Driver Fall Time	t <sub>F</sub>	R <sub>CM</sub> is open, R <sub>L</sub> = 6 10% of transition on			31	ns	
TXD to RXD Loop Delay	t <sub>LOOP</sub>	Dominant to recession dominant, R <sub>L</sub> = 60Ω Figure 2	ive and recessive to , C <sub>L</sub> = 100pF, C <sub>LR</sub> = 15pF,			215	ns
	t <sub>PDTXD_RD</sub> ,	R <sub>CM</sub> is open, R <sub>L</sub> =	Recessive to dominant			80	
TXD Propagation Delay	t <sub>PDTXD_DR</sub>	$60\Omega$ , C <sub>L</sub> = 100pF, Figure 1	Dominant to recessive			80	ns
RXD Propagation Delay	t <sub>PDRXD</sub> RD,	$C_{LR} = 15pF$ ,	Recessive to dominant			135	ns
TOOD I Topagation Delay	t <sub>PDRXD_DR</sub>	Figure 3	Dominant to recessive			135	113
TXD Dominant Timeout	t <sub>DOM</sub>	(Note 7)		1.4	·	4.8	ms
Undervoltage Threshold Detection Time to Normal Operation						120	μs
INSULATION CHARACTERIS	STICS						
Partial Discharge Voltage	$V_{PR}$	Method B1 = V <sub>IORM</sub> x 1.875 (t = 1s, partial discharge < 5pC)			2250		V <sub>P</sub>
Maximum Repetitive Peak Isolation Voltage	V <sub>IORM</sub>	(Note 8)		1200		V <sub>P</sub>	
Maximum Working Isolation Voltage	V <sub>IOWM</sub>	(Note 8)		848		V <sub>RMS</sub>	
Maximum Transient Isolation Voltage	V <sub>IOTM</sub>	t = 1s			8400		V <sub>P</sub>

### **Electrical Characteristics (continued)**

 $(V_{DDA} = 3.0V \text{ to } 5.5V, V_{DDB} = 4.5V \text{ to } 5.5V, POL = GNDA, I.C. = GNDB, T_A = -40^{\circ}C \text{ to } +125^{\circ}C.$  Typical values are at  $V_{DDA} = 3.3V$ ,  $V_{DDB}$  = 5V, GNDA = GNDB, and  $T_A$  = +25°C, unless otherwise noted. (Notes 1, 2)

PARAMETER	SYMBOL	CONDITIONS	MIN TYP MAX	UNITS
Maximum Withstand Isolation Voltage	V <sub>ISO</sub>	t = 60s, f = 60Hz (Notes 8, 9)	5000	V <sub>RMS</sub>
Maximum Surge Isolation Voltage	V <sub>IOSM</sub>	Basic Insulation	10	kV
Insulation Resistance	R <sub>S</sub>	T <sub>A</sub> = +150°C, V <sub>IO</sub> = 500V	>109	Ω
Barrier Capacitance Input-to-Output	CIO	f = 1MHz	2	pF
Minimum Creepage Distance	CPG	Wide SOIC	8	mm
Minimum Clearance Distance	CLR	Wide SOIC	8	mm
Internal Clearance		Distance through insulation	0.015	mm
Comparative Tracking Resistance Index	СТІ	Material Group II (IEC 60112)	575	
Climatic Category			40/125/21	
Pollution Degree (DIN VDE 0110, Table 1)			2	

- Note 1: All devices 100% production tested at  $T_A = +25$ °C. Specifications over temperature are guaranteed by design. Specifications marked "GBD" are guaranteed by design and not production tested.
- Note 2: All currents into the device are positive. All currents out of the device are negative. All voltages referenced to their respective ground (GNDA or GNDB), unless otherwise noted.
- Note 3: The maximum V<sub>LDO</sub> voltage listed in the *Electrical Characteristics* table indicates the voltage capability of the MAX14882. Ambient temperature and power dissipation requirements of a given circuit may limit the allowable maximum V<sub>I DO</sub> to a lower value during operation.
- Note 4: Not production tested. Guaranteed by design (GBD) and characterization.
- Note 5: Capacitance range for a stable output. Values are nominal and allow for normal capacitor tolerance.
- Note 6: CMTI is the maximum sustainable common-mode voltage slew rate while maintaining the correct output states. CMTI applies to both rising and falling common-mode voltage edges. Tested with the transient generator connected between GNDA and GNDB.
- Note 7: The dominant timeout feature releases the bus when TXD is held low longer than t<sub>DOM</sub>. CAN protocol guarantees a maximum of 11 successive dominant bits in any transmission. The minimum data rate allowed by the dominant timeout, then, is 11/t<sub>DOM</sub>(min)
- Note 8:  $V_{IORM}$ ,  $V_{IOWM}$ , and  $V_{ISO}$  are defined by the IEC 60747-5-5 standard Note 9: Product is qualified  $V_{ISO}$  for 60 seconds. 100% production tested at 120% of  $V_{ISO}$  for 1 second.

## **Test Circuits and Timing Diagrams**

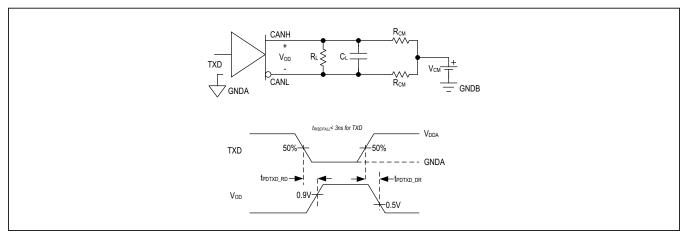


Figure 1. Transmitter Test Circuit and Timing Diagram

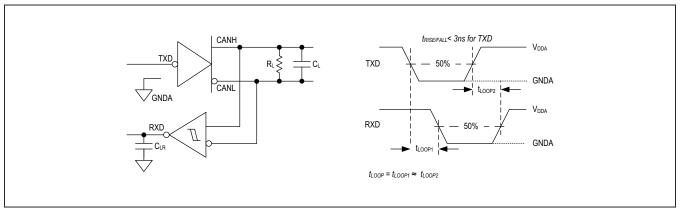


Figure 2. Loop Delay Timing Diagram

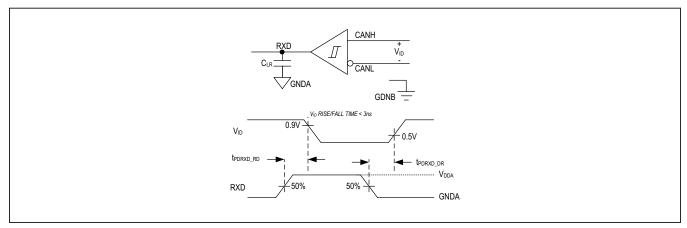
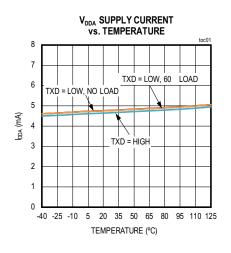
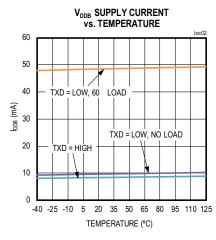


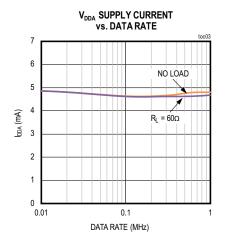
Figure 3. Receiver Timing Diagram

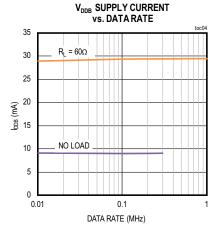
## **Typical Operating Characteristics**

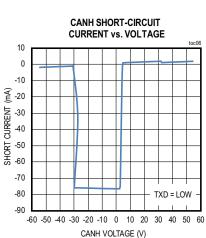
 $V_{DDA}$  = 3.3V to GNDA,  $60\Omega$  load between CANH and CANL, GNDA = GNDB,  $T_A$  = 25°C, unless otherwise noted.

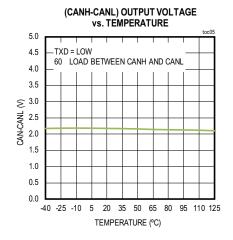


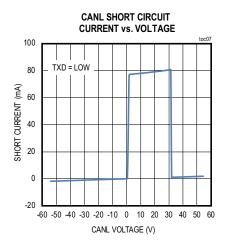






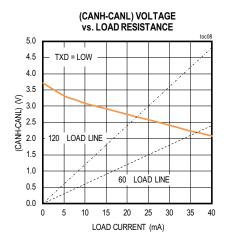


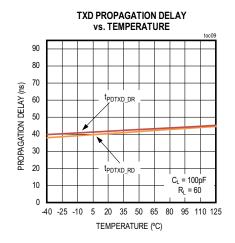


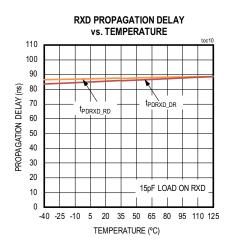


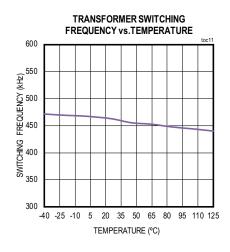
## **Typical Operating Characteristics (continued)**

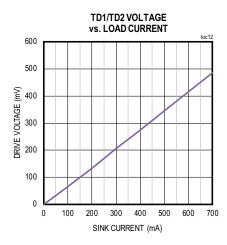
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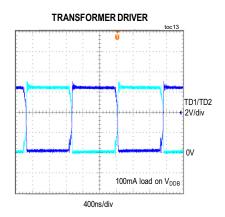




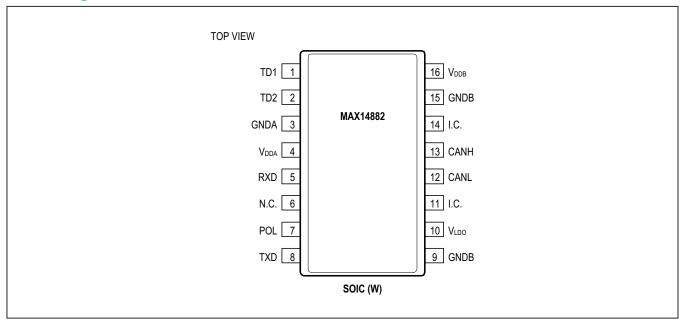








## **Pin Configuration**



## **Pin Description**

PIN	NAME	FUNCTION	REF SUPPLY	TYPE
CONTR	OLLER-S	DE (A-SIDE)		
1	TD1	Transformer Driver Output 1	GNDA	Analog
2	TD2	Transformer Driver Output 2	GNDA	Analog
3	GNDA	Controller-Side/A-Side Ground. GNDA is the ground reference for POL, TXD, and RXD.	_	Ground
4	V <sub>DDA</sub>	Power Supply Input for the Controller-Side/A-Side. Bypass $V_{DDA}$ to GNDA with both a 0.1 $\mu$ F and a 1 $\mu$ F capacitor as close to the device as possible.	GNDA	Power
5	RXD	Receiver Output. RXD is high when the bus is in the recessive state. RXD is low when the bus is in the dominant state.	GNDA	Digital Output
6	N.C.	No Connection. Not internally connected. Connect to GNDA, V <sub>DDA</sub> , or leave unconnected.	GNDA	
7	POL	Polarity Set Input. Drive POL low for normal CANH, CANL operation (CANH is high and CANL is low when TXD is low). Drive POL high to swap the functions of CANH and CANL (CANH is low and CANL is high when TXD is low). See <a href="Table 1">Table 1</a> for more information.	GNDA	Digital Input
8	TXD	Transmit Data Input. CANH and CANL are in the dominant state when TXD is low. CANH and CANL are in the recessive state when TXD is high.	GNDA	Digital Input

### **Pin Description (continued)**

PIN	NAME	FUNCTION	REF SUPPLY	TYPE
CAN BU	IS-SIDE (I	B-SIDE)		
9, 15	GNDB	Bus-Side/B-Side Ground. GNDB is the ground reference for V <sub>LDO</sub> , V <sub>DDB</sub> , CANH, and CANL.	_	Ground
10	V <sub>LDO</sub>	LDO Power Input. Connect a minimum voltage of 4.68V to $V_{LDO}$ to power the bus-side of the transceiver. Bypass $V_{LDO}$ to GNDB with both 0.1 $\mu$ F and 1 $\mu$ F capacitors as close as possible to the device. To disable the internal LDO, leave $V_{LDO}$ unconnected or connect to GNDB.	GNDB	Power Input
11, 14	I.C.	Internally Connected. Connect to GNDB.	GNDB	
12	CANL	Low-Level CAN Differential Bus Line	GNDB	Differential I/O
13	CANH	High-Level CAN Differential Bus Line	GNDB	Differential I/O
16	V <sub>DDB</sub>	Bus-Side Power Input/LDO Power Output. Bypass $V_{DDB}$ to GNDB with both $0.1\mu F$ and $1\mu F$ capacitors as close as possible to the device. $V_{DDB}$ is the output of the internal LDO when power is applied to $V_{LDO}$ . When the internal LDO is not used ( $V_{LDO}$ is unconnected or connected to GNDB), $V_{DDB}$ is the positive supply input for the bus-side of the IC.	GNDB	Power

### **Detailed Description**

The MAX14882 isolated controller area network (CAN) transceiver provides 5000V<sub>RMS</sub> (60s) of galvanic isolation between the cable-side (B-side) of the transceiver and the controller-side (A-side). This device allows up to 1Mbps communication across the isolation barrier when a large potential exists between grounds on each side of the barrier. CANH and CANL outputs are short-circuit current-limited and are protected against excessive power dissipation by thermal shutdown circuitry that places the driver outputs in a high-impedance state.

#### Isolation

Both data and power can be transmitted across the isolation barrier. Data isolation is achieved using integrated capacitive isolation that allows data transmission between the controller-side and the cable-side of the transceiver.

To achieve power isolation, the MAX14882 features an integrated transformer driver to drive an external center-tapped transformer, allowing the transfer of operating power from the controller-side, across the isolation barrier, to the cable-side. Connect the primary side of the external transformer to the MAX14882's transformer driver outputs (TD1 and TD2).

#### **Fault Protection**

The MAX14882 features ±54V fault protection on the CANH and CANL bus lines. When CANH or CANL is pulled above +30V (typ) or below -30V (typ), the I/O is set to high-impedance. This wide fault protection range simplifies selecting external TVS components for surge protection.

#### **Transmitter**

The transmitter converts a single-ended input signal (TXD) from the CAN controller to differential outputs for the bus lines (CANH, CANL). The truth table for the transmitter and receiver is given in Table 1.

#### **Transmitter Dominant Timeout**

The MAX14882 features a transmitter-dominant timeout ( $t_{DOM}$ ) that prevents erroneous CAN controllers from clamping the bus to a dominant level by maintaining a continuous low TXD signal. When TXD remains in the dominant state (low) for greater than  $t_{DOM}$ , the transmitter is disabled, releasing the bus to a recessive state (Table 1).

After a dominant timeout fault, normal transmitter function is re-enabled on the rising edge of a TXD. The transmitter-dominant timeout limits the minimum possible data rate to 7.86kbps for standard CAN protocol.

#### Transmitter and Receiver Functionality When Not Connected to the Bus

Table 1. Transmitter and Receiver Functionality when Not Connected to the Bus

POL	TXD	TXD LOW TIME	CANH	CANL	BUS STATE	RXD
L	L	< t <sub>DOM</sub>	Н	L	Dominant	L
L	L	≥ t <sub>DOM</sub>	V <sub>DDB</sub> /2	V <sub>DDB</sub> /2	Recessive	Н
L	Н	X	V <sub>DDB</sub> /2	V <sub>DDB</sub> /2	Recessive	Н
Н	L	< t <sub>DOM</sub>	L	Н	Dominant	L
Н	L	≥ t <sub>DOM</sub>	V <sub>DDB</sub> /2	V <sub>DDB</sub> /2	Recessive	Н
Н	Н	X	V <sub>DDB</sub> /2	V <sub>DDB</sub> /2	Recessive	Н
X = Don't care						

### **Driver Output Protection**

The MAX14882 features integrated circuitry to protect the transmitter output stage against a short-circuit to a positive or negative voltage by limiting the driver current. The transmitter returns to normal operation once the short is removed.

Thermal shutdown further protects the transceiver from excessive temperatures that may result from a short by setting the transmitter outputs to high impedance when the junction temperature exceeds +160°C (typ). The transmitter returns to normal operation when the junction temperature falls below the thermal shutdown hysteresis.

### Receiver

The receiver reads the differential input from the bus (CANH, CANL) and transfers this data as a single-ended output (RXD) to the CAN controller. During normal operation, a comparator senses the difference between CANH and CANL,  $V_{DIFF} = |V_{CANH} - V_{CANL}|$ , with respect to an internal threshold of 0.7V (typ). If  $V_{DIFF} > 0.9$ V, a logic-low is present on RXD. If  $V_{DIFF} < 0.5$ V, a logic-high is present.

The CANH and CANL common-mode range is ±25V. RXD is logic-high when CANH and CANL are shorted or terminated and undriven.

#### **Transformer Driver**

### **Overcurrent Limiting**

The MAX14882 features overcurrent limiting to protect the integrated transformer driver from excessive currents when charging large capacitive loads or driving into shortcircuits. Current limiting is achieved in two stages: internal circuitry monitors the output current and detects when the peak current rises above 1.2A.

When the 1.2A threshold is exceeded, internal circuitry reduces the output current to the 730mA current-limit. The MAX14882 monitor the driver current on a cycle-by-cycle basis and limit the current until the short is removed.

The transformer driver on the MAX14882 can dissipate large amounts of power during overcurrent limiting, causing the IC to enter thermal shutdown. When the junction temperature exceeds the thermal shutdown threshold, the TD1 and TD2 driver outputs are disabled. The driver resumes normal operation when the temperature falls below the thermal shutdown temperature minus the hysteresis.

### MAX14882

## with Integrated Transformer Driver

#### **Transformer Selection**

The integrated push-pull transformer driver allows the transmission of operating power from the logic side, across the isolation barrier, to the isolated field side of the device. The 450kHz (typ) transformer driver operates with center-tapped primary transformers. Select a transformer with an ET product greater than or equal to the ET of the driver to ensure that the transformer does not enter saturation. E is the voltage applied to the transformer and T is the maximum time it is applied during any one cycle. Calculate the minimum ET product for the transformer primary as:

$$ET = V_{MAX}/(2 \times f_{MIN})$$

where  $V_{MAX}$  is the worst-case maximum supply voltage on  $V_{DDA}$  and  $f_{MIN}$  is the minimum frequency at that supply voltage. For example, using 5.5V and 350kHz, the required minimum ET product is 7.9V $\mu$ s.

<u>Table 2</u> shows a list of recommended transformers to use with the MAX14882.

### **Applications Information**

#### **Reduced EMI and Reflections**

In multidrop CAN applications, it is important to maintain a single linear bus, of uniform impedance, that is properly terminated at each end. Do not use a star configuration.

5kV<sub>RMS</sub> Isolated CAN Transceiver

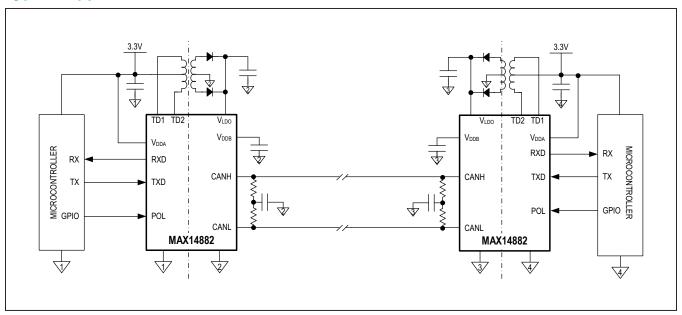
Any deviation from the end-to-end wiring scheme creates a stub. High-speed data edges on a stub can create reflections back down the bus and can cause data errors, by eroding the noise margin of the system. Although stubs are unavoidable in a multidrop system, care should be taken to keep these stubs as short as possible, especially when operating with high data rates.

### **Recommended Transformers**

**Table 2. Recommended Transformers** 

MANUFACTURER	PART NUMBER	APPLICATION	TURNS RATIO	ISOLATION (V <sub>RMS</sub> )	OPERATING TEMP	ET CONSTANT (V x µs, MIN)	OPERATING CURRENT (mA)	DIMENSIONS (L x W x H) (mm)
Wurth	750315225	5V to 5V	1CT:1.1CT	2750		9.44	200	6.73 x 7.14 x 4.19
Wurth	750315226	5V to 5V	1CT:1.3CT	2750	-40°C to	9.44	200	6.73 x 7.14 x 4.19
Wurth	750315227	3.3V to 5V	1CT:1.7CT	2750	+125°C	9.44	200	6.73 x 7.14 x 4.19
Wurth	750315228	3.3V to 5V	1CT:2CT	2750		9.44	160	6.73 x 7.14 x 4.19
Wurth	750315229	5V to 5V	1CT:1.13CT	5000	-40°C to	10.7	200	9.14 x 8.00 x 7.62
Wurth	750315230	5V to 5V	1CT:1.38CT	5000	+125°C	10.7	150	9.14 x 8.00 x 7.62

## **Typical Application Circuit**



## **Ordering Information**

PART	ISOLATION RATING	V <sub>DDA</sub> SUPPLY	POL	V <sub>DDB</sub> LDO VOLTAGE	TRANSFORMER DRIVER	PACKAGE
MAX14882AWE+	5kV <sub>RMS</sub>	3.0V to 5.5V	YES	5V	YES	16 SOIC (W)
MAX14882AWE+T	5kV <sub>RMS</sub>	3.0V to 5.5V	YES	5V	YES	16 SOIC (W)

<sup>+</sup>Denotes a lead (Pb)-free/RoHS-compliant package

T = Tape and Reel